NSN 5961-01-125-5879

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View Online at https://aerobasegroup.com/nsn/5961-01-125-5879 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **Overall Diameter:** 0.875 inches **End Application:** Lighting system 76301 **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 collector to emitter voltage/static/base open and 600.0 breakdown voltage, collector-to-base, emitter open and 20.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 15.00 amperes source cutoff current and 4.00 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: